

PATENT  
81912.0017  
Express Mail Label No. EV 324 111 429 US

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:  
  
Hideto SUGAWARA  
  
Serial No: Not assigned  
  
Filed: December 9, 2003  
  
For: Nitride Based Semiconductor Light-Emitting Device  
and Method of Manufacturing the Same

Art Unit: Not assigned  
  
Examiner: Not assigned

**TRANSMITTAL OF INFORMATION DISCLOSURE**  
**STATEMENT**

Mail Stop PATENT APPLICATION  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

Dear Sir:

The information disclosure statement submitted herewith is being filed concurrently with the subject application [37 C.F.R. § 1.97(b)] and contains no items of information cited in any communication from a foreign patent office in a counterpart foreign application [37 C.F.R. § 1.97(e)(1)].

If it should be determined that for any reason either an insufficient or excessive fee has been paid, please charge any insufficiency or credit any overpayment necessary to ensure consideration of the information disclosure statement for the above-identified application to Deposit Account No. 50-1314. A copy of this paper is enclosed.

Respectfully submitted,

HOGAN & HARTSON L.L.P.

By:   
Anthony J. Orler  
Registration No. 41,232  
Attorney for Applicant(s)

Date: December 9, 2003

500 South Grand Avenue, Suite 1900  
Los Angeles, California 90071  
Telephone: 213-337-6700  
Facsimile: 213-337-6701

FORM PTO-1449		Docket Number (Optional) 81912.0017		Application Number Not assigned	
<b>INFORMATION DISCLOSURE CITATION IN AN APPLICATION</b>		Applicant Hideto SUGAWARA			
(Use several sheets if necessary)		Filing Date December 9, 2003		Group Art Unit Not assigned	
<b>U.S. PATENT DOCUMENTS</b>					
EXAMINER INITIAL	DOCUMENT NUMBER	DATE	NAME	CLASS	SUBCLASS
<b>FOREIGN PATENT DOCUMENTS</b>					
	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUBCLASS
	2002-016312	01/18/02	Japan		
<b>OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)</b>					
EXAMINER		DATE CONSIDERED			